

Product Description

The PE42742 is an SPDT UltraCMOS™ Switch designed for Broadband applications such as CATV, DTV, Multi-Tuner DVR (Digital Video Recorder), Set-top Box, PCTV and Game Boxes. It meets FCC 15.115 spec of 80 dB isolation @ 216 MHz and offers high isolation and low insertion loss in both a powered and a unique unpowered default state. The PE42742 covers a broad frequency range from near DC to beyond 2200 MHz with a single positive supply and CMOS control. It provides a smaller, cost effective, more reliable and manufacturable alternative to mechanical relays in settop box applications.

The PE42742 is manufactured on Peregrine's UltraCMOS™ process, a patented variation of silicon-on-insulator (SOI) technology on a sapphire substrate, offering the performance of GaAs with the economy and integration of conventional CMOS.

Product Specification PE42742

75 Ω Terminated - 2200 MHz SPDT **CATV UltraCMOS™ Switch Featuring Unpowered Operation**

Features

- Meets FCC 15.115 spec of 80 dB isolation @ 216 MHz
- Unpowered operational state
- 2000 V HBM ESD tolerance, RF Pins
- CTB performance of 90 dBc
- High isolation: 63 dB at 1000 MHz
- Low insertion loss: typically 0.5 dB at 5 MHz, 0.8 dB at 1000 MHz
- CMOS single-pin control with logic select
- Single +3 volt supply operation
- Low current consumption: 8 μA

Figure 1. Functional Diagram

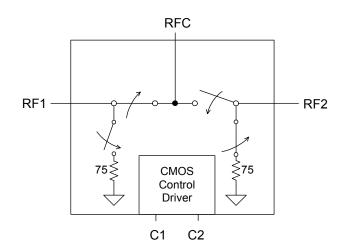


Figure 2. Package Type

4x4 mm 20-lead QFN





Table 1. Electrical Specifications @ +25 °C, V_{DD} = +3 V (Z_S = Z_L = 75 Ω)

Parameter	Condition	Minimum	Typical	Maximum	Units
Operating Frequency		5		2200	MHz
	220 MHz		0.45	0.55	dB
RF1-RFC Insertion Loss	550 MHz		0.55	0.65	dB
RF1-RFC IIISeIIIOII LOSS	810 MHz		0.7	0.8	dB
	2200 MHz		1.7	1.8	dB
	220 MHz		0.7	0.8	dB
RF2-RFC Insertion Loss	550 MHz		8.0	0.9	dB
IXI Z-IXI C IIISGIIIOII E033	810 MHz		0.9	1	dB
	2200 MHz		1.8	1.9	dB
	220 MHz	81	94		dB
Isolation RF1 to RF2 (RFC-RF1 ON)	550 MHz	77	82		dB
isolation in the first 2 (in o in i on)	810 MHz	71.5	76		dB
	2200 MHz	50	53.6		dB
	220 MHz	81	92		dB
Isolation RF1 to RF2 (RFC-RF2 ON)	550 MHz	75	79		dB
1501ation 11 1 10 11 2 (11 0 11 2 014)	810 MHz	70.5	75		dB
	2200 MHz	50	53		dB
	220 MHz	71	74		dB
Isolation RF1 to RFC (RFC-RF2 ON)	550 MHz	64	66		dB
	810 MHz	62	64		dB
	2200 MHz	52	57		dB
	220 MHz	70.5	73		dB
Isolation RF2 to RFC (RFC-RF1 ON)	550 MHz	64	66		dB
	810 MHz	61.5	63		dB
	2200 MHz	51	55		dB
IP2 RF1/RF2 ²	5 MHz – 1000 MHz		90/90		dBm
IIP3 RF1/RF2 ²	5 MHz – 1000 MHz		53/53		dBm
Input 1 dB Compression RF1/RF2 ²	1000 MHz	30/24.5	32/26.5		dBm
CTB / CSO (Powered/Unpowered)	77 & 110 channels; Power Out = 44 dBmV		-90 / -77		dBc
Switching time	50 % CTRL to 10 / 90 RF		3		μs
Video Feedthough³	5 MHz – 1000MHz		20		mVpp

Table 2. Electrical Characterization (Unpowered Operation)⁵

Parameter	Condition	Minimum	Typical	Maximum	Units
Operating Frequency ¹		5		2200	MHz
	220 MHz	81	90.5	-	dB
location DE4 to DE24	550 MHz	77	81.5	-	dB
Isolation RF1 to RF2 ⁴	810 MHz	70.5	77	-	dB
	2200 MHz	49	52.5	-	dB

Notes: 1. Device linearity will begin to degrade with input signals below 5 MHz. 2. Measured in a 50 Ω system.

- 3. Measured with a 1 ns risetime, $0/3\ V$ pulse and 500 MHz bandwidth
- 4. Minimum per FCC 15.115 spec
- 5. See figure 9 for Power-Off insertion loss of RFC-RF1

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Figure 3. Pin Configuration (Top View)

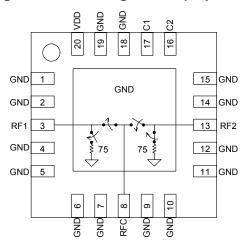


Table 3. Pin Descriptions

No.	Name	Description
1	GND	RF Ground
2	GND	RF Ground
3	RF1 ¹	RF I/O
4	GND	RF Ground
5	GND	RF Ground
6	GND	RF Ground
7	GND	RF Ground
8	RFC ¹	RF Common
9	GND	RF Ground
10	GND	RF Ground
11	GND	RF Ground
12	GND	RF Ground
13	RF2 ¹	RF I/O
14	GND	RF Ground
15	GND	RF Ground
16	C2 ²	Control 2 (or logic select)
17	C1 ²	Control 1 (or logic select)
18	GND	RF Ground
19	GND	RF Ground
20	VDD	Supply
Pad	GND	RF Ground Pad

Notes:

1. RF pins 3, 8, and 13 must be at 0 VDC. The RF pins do not require DC blocking capacitors for proper operation if the 0 V DC requirement is met.

2. Pins 16 and 17 can be set for single pin or complementary pin control.

Table 4. Operating Conditions @ 25 °C

Parameter	Min	Тур	Max	Unit
V _{DD} Power Supply	2.7	3.0	3.3	٧
I_{DD} Power Supply Current $(V_{DD} = 3 \text{ V}, V_{CNTL} = 3 \text{ V})$		8		μΑ
Control Voltage High	0.7 x V _{DD}		V_{DD}	V
Control Voltage Low	0		0.3 x V _{DD}	V

Table 5. Absolute Maximum Ratings

Symbol	Parameter/Condition	Min	Max	Unit
V_{DD}	Power supply voltage	-0.3	4.0	٧
Vı	Voltage on any DC input	-0.3	V _{DD} + 0.3	V
P _{RF}	RF power on RFC, RF1, RF2 Terminated/Through		24/33	dBm
T _{ST}	Storage temperature	-65	+150	°C
T _{OP}	Operating temperature	-40	+85	°C
V _{ESD}	ESD Voltage* RF Pins		2000	V
	ESD Voltage* Digital Pins		500	V

^{*}HBM, ML_STD 883 Method 3015.7

Exceeding absolute maximum ratings may cause permanent damage. Operation should be restricted to the limits in the Operating Ranges table. Operation between operating range maximum and absolute maximum for extended periods may reduce reliability.

Electrostatic Discharge (ESD) Precautions

When handling this UltraCMOS™ device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the rating specified.

Latch-Up Avoidance

Unlike conventional CMOS devices, UltraCMOS™ devices are immune to latch-up.

Switching Frequency

The PE42742 has a maximum 25 kHz switching rate.



Table 6. Truth Table

V _{DD}	C1 (pin 17)	C2 (pin 16)	RFC – RF1	RFC – RF2
OFF	Low	Low	ON	OFF
ON	Low	Low	ON	OFF
ON	Low	High	OFF	ON
ON	High	Low	OFF	ON
ON	High	High	ON	OFF

Note: A versatile logic table has been established to allow either C1 or C2 act as a single pin control and in either polarity.

Figure 4. Typical Application (1 of 4)

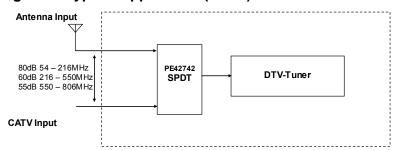


Figure 5. Typical Application (2 of 4)

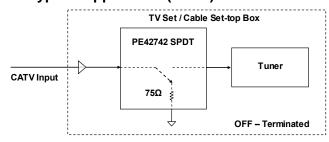


Figure 6. Typical Application (3 of 4)

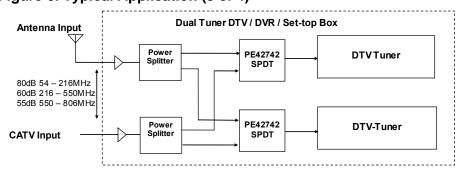
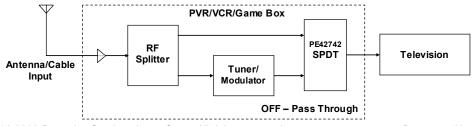


Figure 7. Typical Application (4 of 4)



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Typical Applications

C1=C2 (both high or low).

The PE42742 provides the high isolation required by FCC part 15.115 regulation between the television antenna and the cable plant. The advantage of the PE42742 is that device

isolation / thru performance is maintained when power is removed. This unique feature makes the

applications. The PE42742 supports signal flow from RFC to RF1 and RF2 termination in the

unpowered state; similar to the powered state with

PE42742 ideal for set-top box and VCR

UltraCMOS™ RFIC Solutions



Typical Performance Data @ 25°C, 75 Ω

Figure 8. Insertion Loss - Power On

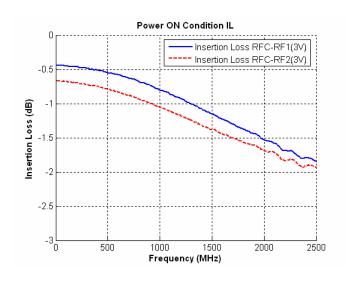


Figure 9. Insertion Loss - Power Off

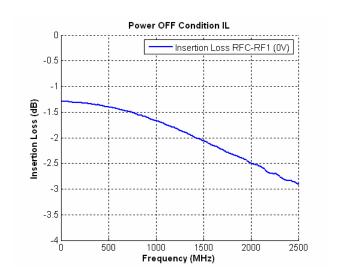


Figure 10. Isolation - Power On

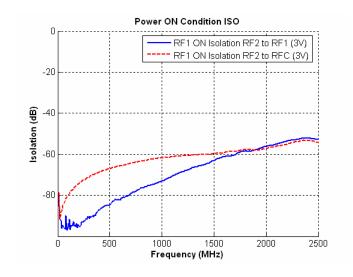
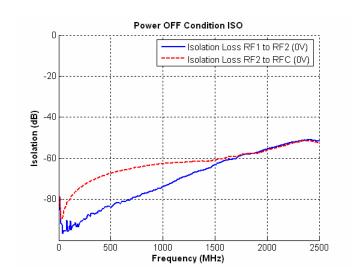


Figure 11. Isolation - Power Off





Typical Performance Data @ 25°C, 75 Ω

Figure 12. Isolation: RF2 - Power On

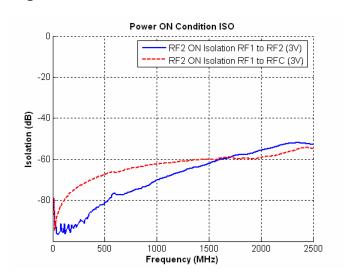


Figure 13. Return Loss: RF1

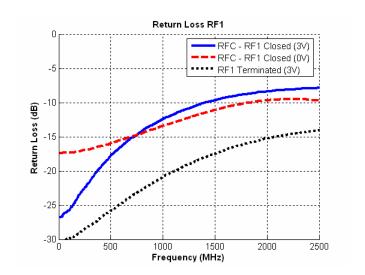


Figure 14. Return Loss: RF2

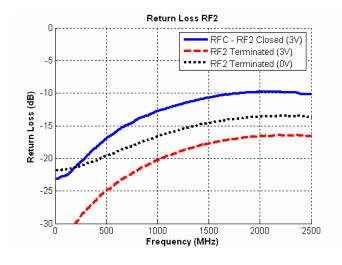
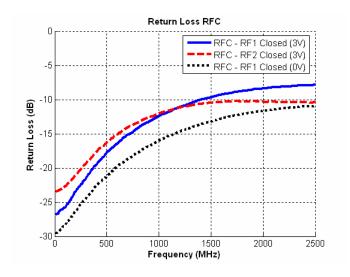


Figure 15. Return Loss: RFC



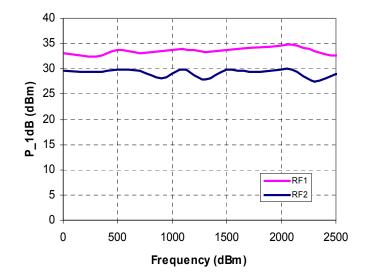


Typical Performance Data @ 25°C, 75 Ω

Figure 16. Input IP3: RFC-RF1/RF2

70 60 50 Input IP3 (dBm) 40 30 20 RF1 10 RF2 0 0 500 1000 1500 2000 2500 Frquency (MHz)

Figure 17. P_1dB Compression: RFC-RF1/RF2





Evaluation Kit

The SPDT Switch Evaluation Kit facilitates customer evaluation of the PE42742 SPDT switch. The RF common port is connected through a 75 Ω transmission line to J2. Ports 1 and 2 are connected through 75 Ω transmission lines to J1 and J3. A through line connects F connectors J4 and J5. This transmission line can be used to estimate the PCB loss over the environmental conditions. J6 provides DC and digital inputs to the device.

The board is composed of a two metal layer FR4 material with a total thickness of 0.032". The transmission lines are hybrid microstrip/coplanar waveguide with ground plane (28 mil core, 12 mil width, 12 mil gap).

The provided jumpers short the control pins to ground for logic low. With the jumper removed the control input rises to V_{DD} for logic high through the 1 M Ω pull up resistor. These resistors will draw several microamps from V_{DD.} They are not required for normal operation.

Figure 18. Evaluation Board Layouts

Peregrine Specification 101/0269

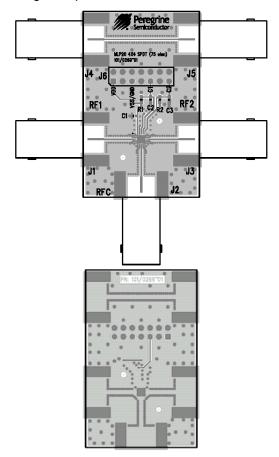


Figure 19. Peregrine Specification 102/0352

GND GND U1 PE4274 or PE42742 GND GNE QVS

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Evaluation Board



Figure 20. Package Drawing

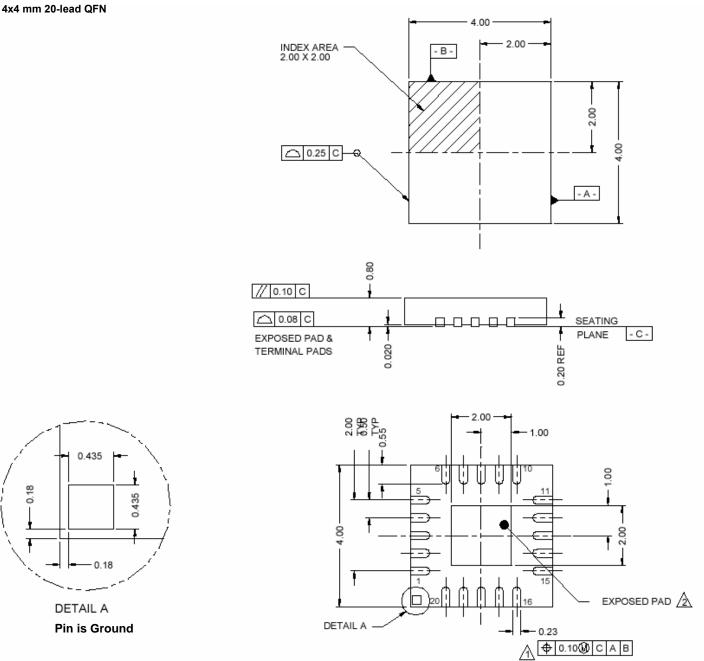




Figure 21. Marking Specification



YYWW = Date Code (Year, Work Week) ZZZZZ = Last five digits of PSC Lot Number

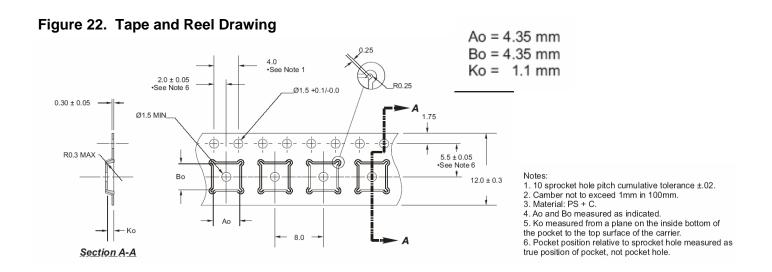


Table 7. Ordering Information

Order Code	Part Marking	Description	Package	Shipping Method
42742-00	PE42742-EK	PE42742-20 QFN 4x4mm-EK	Evaluation Kit	1 / Box
42742-51	42742	PE42742G-20 QFN 4x4mm-75A	Green 20-lead 4x4mm QFN	75 units / Tube
42742-52	42742	PE42742G-20 QFN 4x4mm-3000C	Green 20-lead 4x4mm QFN	3000 units / T&R



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Data Sheet Identification

Advance Information

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